IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application No.:

10/553,573

Applicants:

Christian DUSSARRAT, et al.

Filed Internationally:

April 8, 2004

US National:

October 17, 2005

Title:

METHODS FOR PRODUCING SILICON NITRIDE FILMS

BY VAPOR-PHASE GROWTH

TC/A.U.:

1762

Examiner:

Elizabeth A. Burkhart

Docket No.:

Serie 6070

Customer No.:

40582

AMENDMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In response to the Office Action of January 5, 2009, please amend the application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims begin on page 3 of this paper.

Remarks begin on page 8 of this paper.